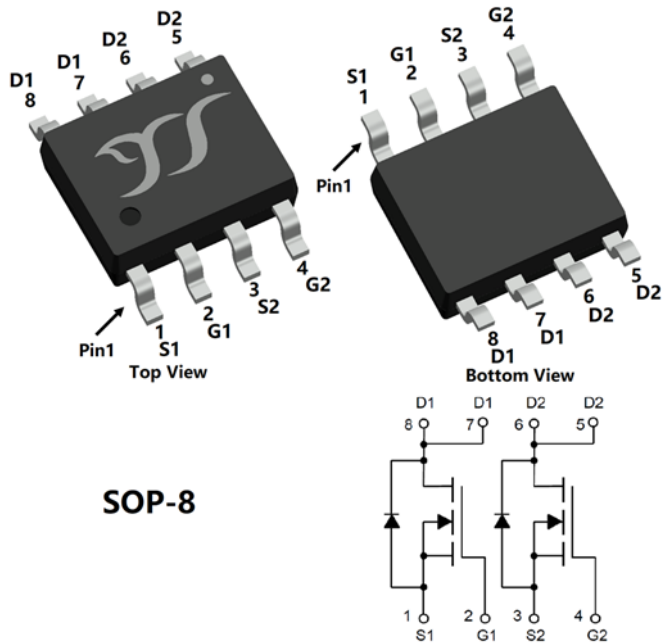


## N-Channel Enhancement Mode Field Effect Transistor



### Product Summary

- $V_{DS}$  60V
- $I_D$  5.0A
- $R_{DS(ON)}$ ( at  $V_{GS}=10V$ ) <44mohm
- $R_{DS(ON)}$ ( at  $V_{GS}=4.5V$ ) <49mohm

### General Description

- Trench Power MV MOSFET technology
- High density cell design for Low  $R_{DS(ON)}$
- High Speed switching
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

### Applications

- Battery protection
- Load switch
- Power management

### ■ Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| Parameter  | Symbol          | Maximum                               | Unit                      |
|--|-----------------|---------------------------------------|---------------------------|
| Drain-source Voltage   | $V_{DS}$        | 60                                    | V                         |
| Gate-source Voltage  | $V_{GS}$        | $\pm 20$                              | V                         |
| Drain Current  | $I_D$           | $T_A=25^\circ\text{C}$ @ Steady State | 5.0                       |
|  |                 | $T_A=70^\circ\text{C}$ @ Steady State | 4.0                       |
| Pulsed Drain Current <sup>A</sup>                                  | $I_{DM}$        | 25                                    | A                         |
| Total Power Dissipation @ $T_A=25^\circ\text{C}$                   | $P_D$           | 3.1                                   | W                         |
| Thermal Resistance Junction-to-Ambient @ Steady State <sup>B</sup> | $R_{\theta JA}$ | 40.3                                  | $^\circ\text{C}/\text{W}$ |
| Junction and Storage Temperature Range                             | $T_J, T_{STG}$  | -55~+150                              | $^\circ\text{C}$          |

### ■ Ordering Information (Example)

| PREFERRED P/N | PACKING CODE | Marking | MINIMUM PACKAGE(pcs) | INNER BOX QUANTITY(pcs) | OUTER CARTON QUANTITY(pcs) | DELIVERY MODE |
|---------------|--------------|---------|----------------------|-------------------------|----------------------------|---------------|
| YJS05N06A     | F2           | Q05N06  | 4000                 | 8000                    | 64000                      | 13" reel      |



# YJS05N06A

## ■ Electrical Characteristics ( $T_J=25^\circ\text{C}$ unless otherwise noted)

| Parameter                             | Symbol       | Conditions   | Min | Typ  | Max       | Units      |
|---------------------------------------|--------------|--|-----|------|-----------|------------|
| <b>Static Parameter</b>               |              |  |     |      |           |            |
| Drain-Source Breakdown Voltage        | $BV_{DSS}$   | $V_{GS}=0V, I_D=250\mu A$  | 60  |      |           | V          |
| Zero Gate Voltage Drain Current       | $I_{DSS}$    | $V_{DS}=60V, V_{GS}=0V$  |     |      | 1         | $\mu A$    |
| Gate-Body Leakage Current             | $I_{GSS}$    | $V_{GS}=\pm 20V, V_{DS}=0V$  |     |      | $\pm 100$ | nA         |
| Gate Threshold Voltage                | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$                                      | 1.0 | 1.5  | 2.5       | V          |
| Static Drain-Source On-Resistance     | $R_{DS(on)}$ | $V_{GS}=10V, I_D=5.0A$   |     | 35   | 44        | m $\Omega$ |
|                                       |              | $V_{GS}=4.5V, I_D=4.0A$  |     | 39   | 49        |            |
| Diode Forward Voltage                 | $V_{SD}$     | $I_S=5.0A, V_{GS}=0V$  |     | 0.8  | 1.2       | V          |
| Maximum Body-Diode Continuous Current | $I_S$        |  |     |      | 5.0       | A          |
| <b>Dynamic Parameters</b>             |              |  |     |      |           |            |
| Input Capacitance                     | $C_{iss}$    | $V_{DS}=30V, V_{GS}=0V, f=1\text{MHz}$                             |     | 1018 |           | pF         |
| Output Capacitance                    | $C_{oss}$    |  |     | 70   |           |            |
| Reverse Transfer Capacitance          | $C_{rss}$    |  |     | 62   |           |            |
| <b>Switching Parameters</b>           |              |  |     |      |           |            |
| Total Gate Charge                     | $Q_g$        | $V_{GS}=10V, V_{DS}=30V, I_D=10A$                                  |     | 26   |           | nC         |
| Gate Source Charge                    | $Q_{gs}$     |  |     | 5.4  |           |            |
| Gate Drain Charge                     | $Q_{gd}$     |  |     | 6.5  |           |            |
| Reverse Recovery Charge               | $Q_{rr}$     | $I_F=20A, di/dt=500A/\mu s$  |     | 11.7 |           | ns         |
| Reverse Recovery Time                 | $t_{rr}$     |  |     | 23   |           |            |
| Turn-on Delay Time                    | $t_{D(on)}$  | $V_{GS}=10V, V_{DD}=30V, I_D=2A, R_L=1\Omega$<br>$R_{GEN}=3\Omega$ |     | 10   |           | ns         |
| Turn-on Rise Time                     | $t_r$        |  |     | 20   |           |            |
| Turn-off Delay Time                   | $t_{D(off)}$ |  |     | 29   |           |            |
| Turn-off Fall Time                    | $t_f$        |  |     | 21   |           |            |

A. Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$ .

B.  $R_{\theta JA}$  is the sum of the junction-to-lead and lead-to-ambient thermal resistance, where the lead thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JL}$  is guaranteed by design, while  $R_{\theta JA}$  is determined by the board design. The maximum rating presented here is based on mounting on a 1 in 2 pad of 2oz copper.



## ■ Typical Performance Characteristics

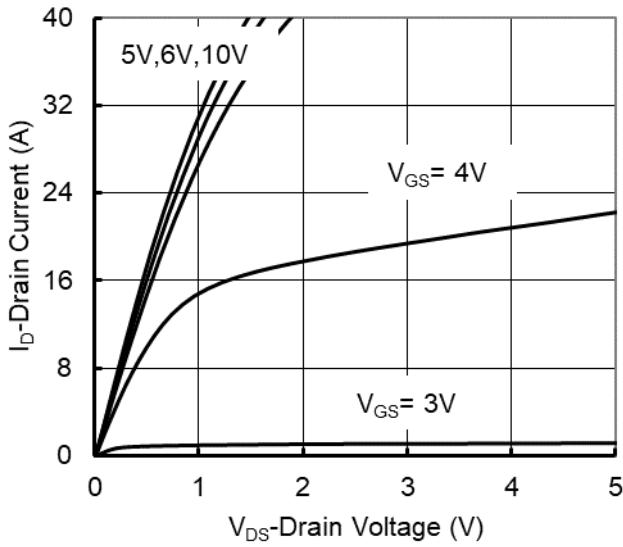


Figure 1. Output Characteristics

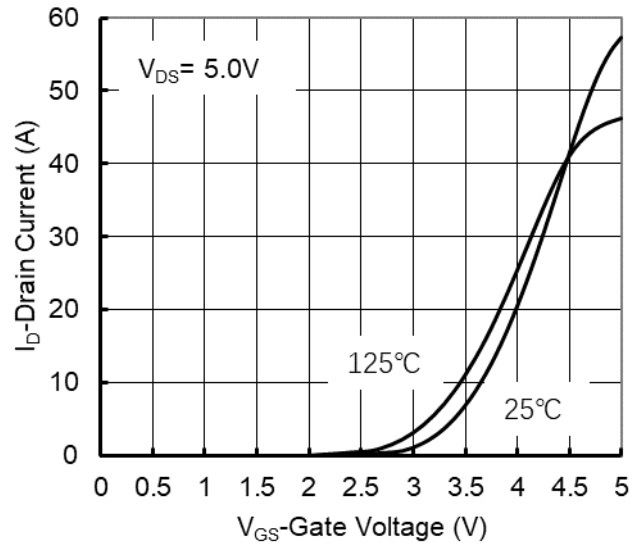


Figure 2. Transfer Characteristics

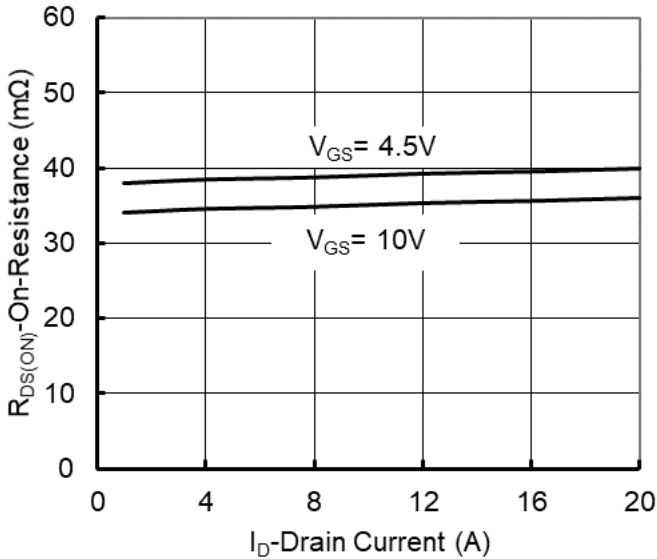


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

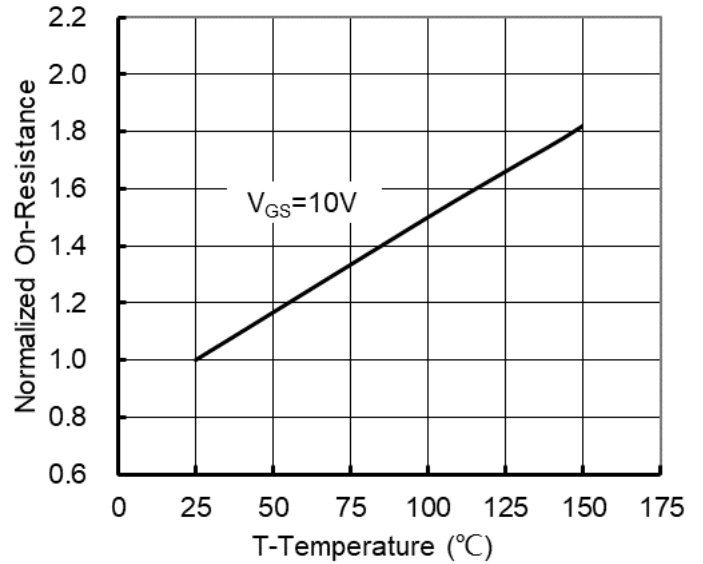


Figure 4. On-Resistance vs. Junction Temperature

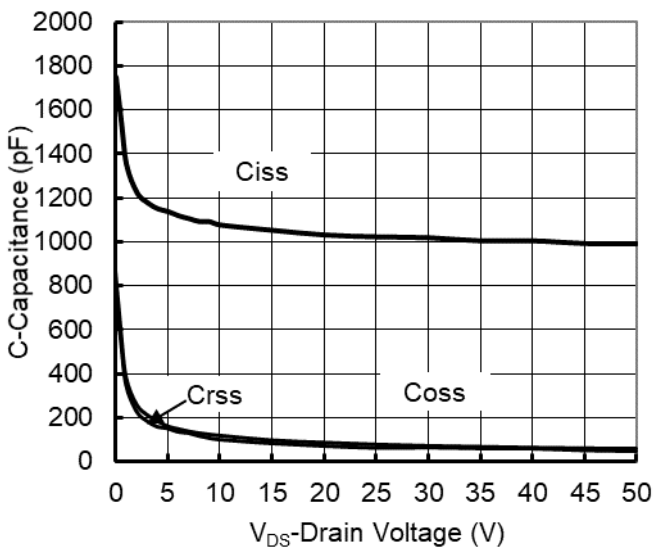


Figure 5. Capacitance Characteristics

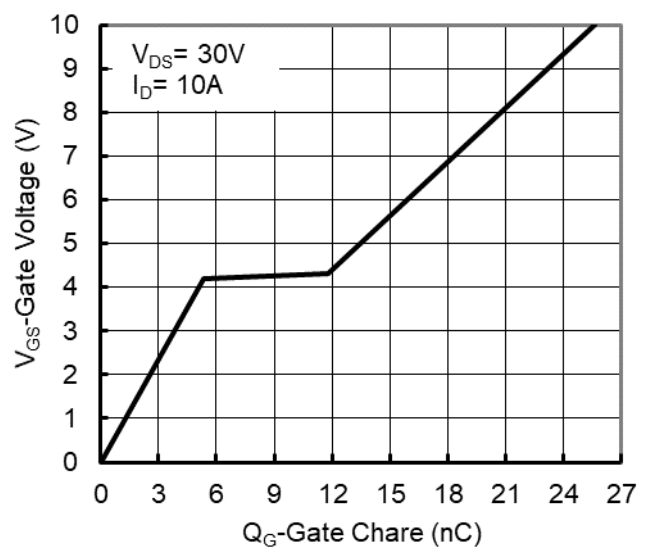


Figure 6. Gate Charge



# YJS05N06A

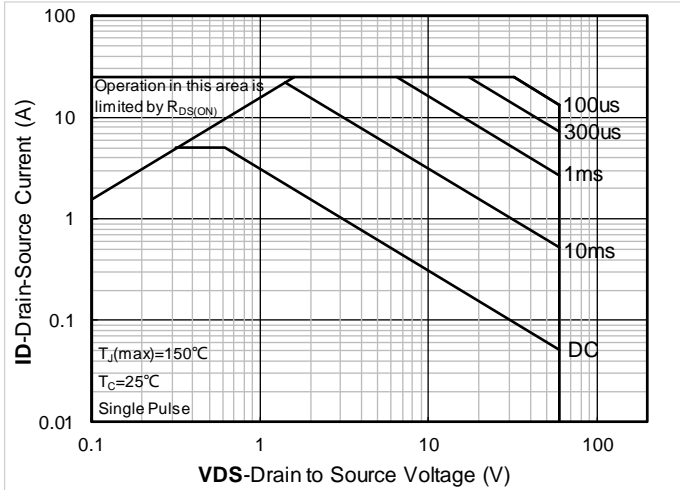


Figure 7. Safe Operation Area

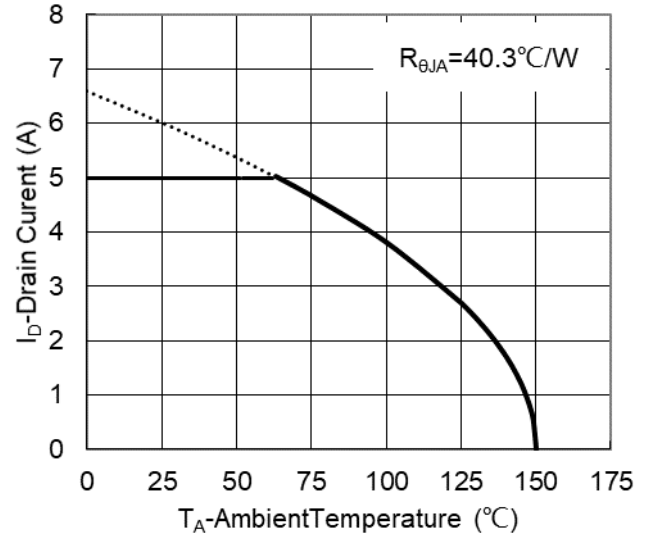


Figure 8. Maximum Continuous Drain Current vs Ambient Temperature

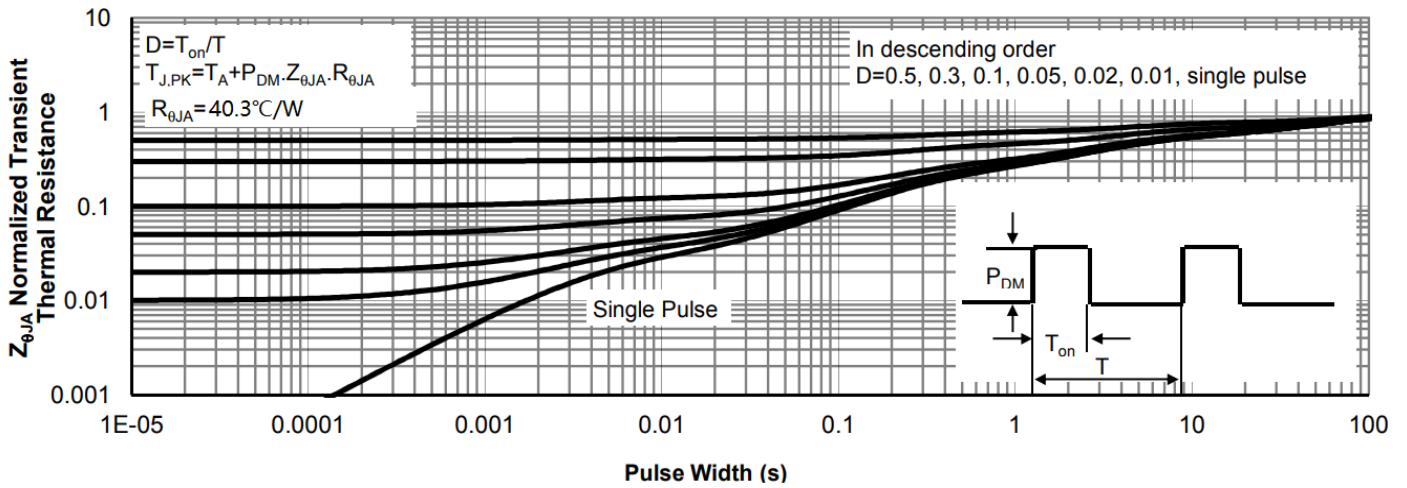
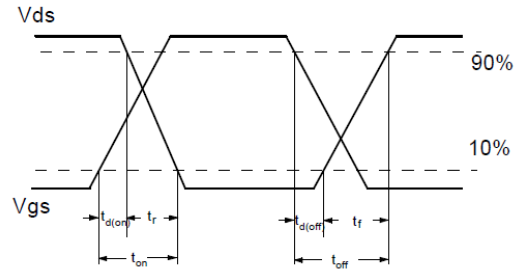
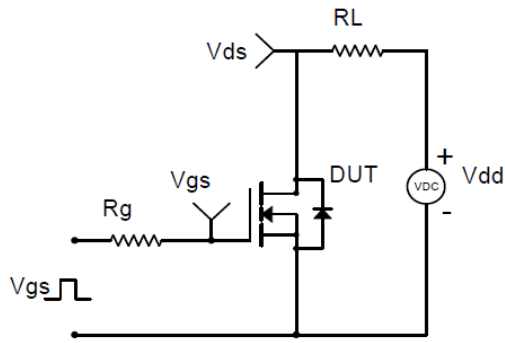
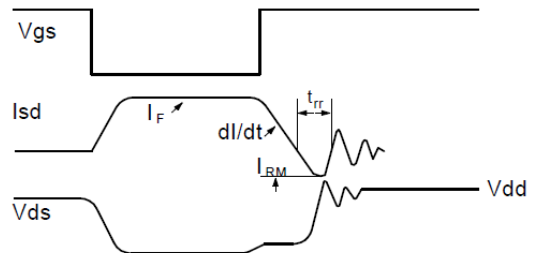
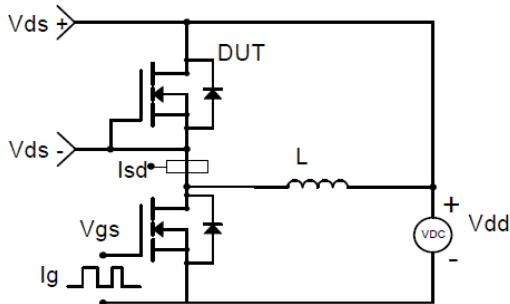


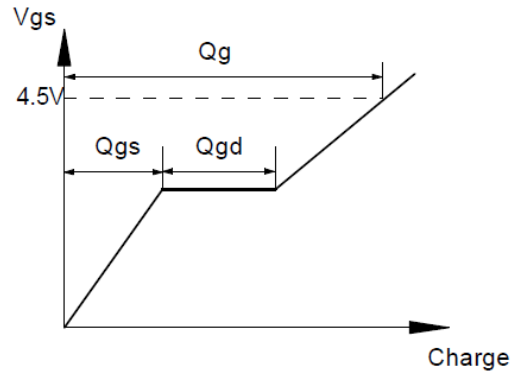
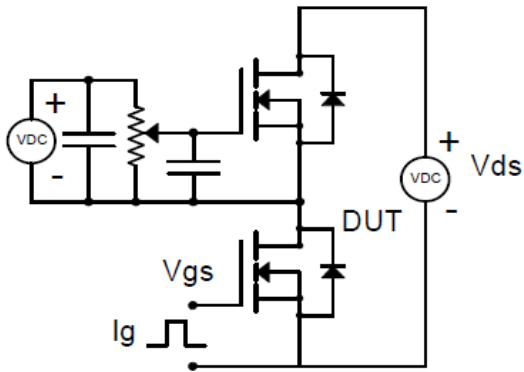
Figure 9. Normalized Maximum Transient Thermal Impedance



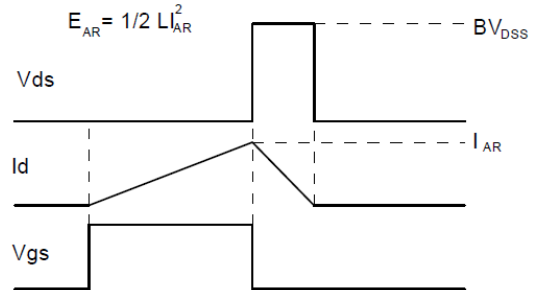
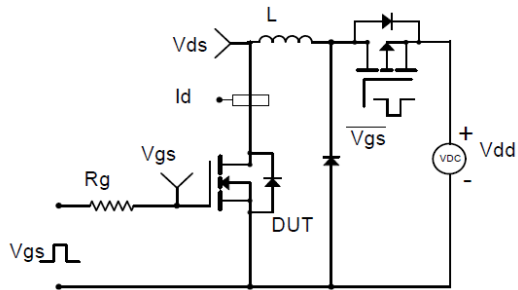
**Resistive Switching Test Circuit & Waveforms**



**Diode Recovery Test Circuit & Waveforms**



**Gate Charge Test Circuit & Waveform**

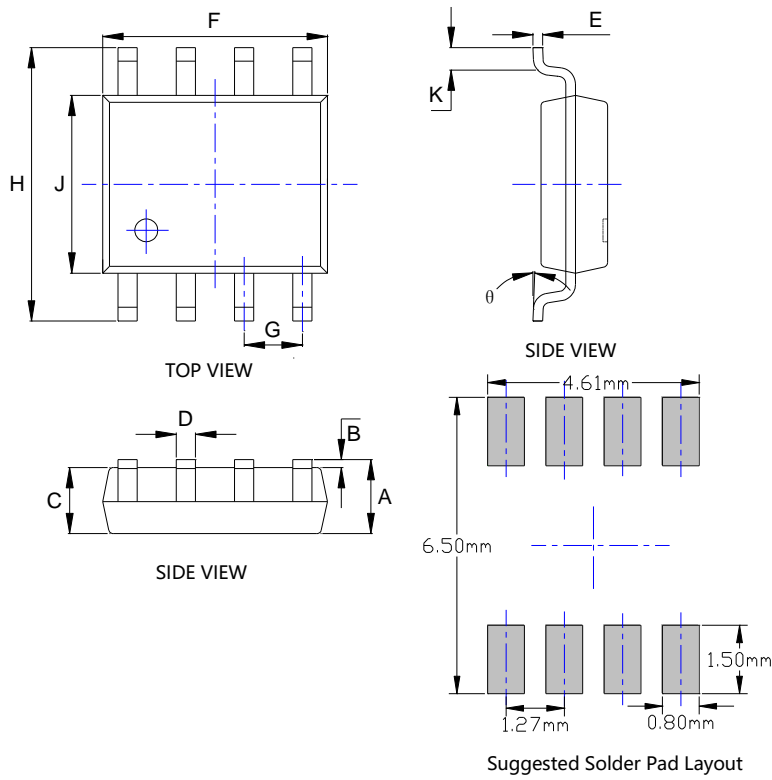


**Unclamped Inductive Switching (UIS) Test Circuit & Waveforms**



# YJS05N06A

## ■SOP-8 Package information



| SYMBOL   | DIMENSIONS |       |            |       |
|----------|------------|-------|------------|-------|
|          | INCHES     |       | Millimeter |       |
|          | MIN.       | MAX.  | MIN.       | MAX.  |
| A        | 0.053      | 0.069 | 1.350      | 1.750 |
| B        | 0.004      | 0.010 | 0.100      | 0.250 |
| C        | 0.053      | 0.061 | 1.350      | 1.550 |
| D        | 0.013      | 0.020 | 0.330      | 0.510 |
| E        | 0.007      | 0.010 | 0.170      | 0.250 |
| F        | 0.189      | 0.197 | 4.800      | 5.000 |
| G        | 0.050BSC   |       | 1.270BSC   |       |
| H        | 0.228      | 0.244 | 5.800      | 6.200 |
| J        | 0.150      | 0.157 | 3.800      | 4.000 |
| K        | 0.016      | 0.050 | 0.400      | 1.270 |
| $\theta$ | 0°         | 8°    | 0°         | 8°    |

### Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.



## YJS05N06A

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